

Development of An Integrated Circuits for Non-Isolated DC-DC Converters

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Abstract—Non-isolated buck circuit, boost circuit, buck/boost circuit and Cuk circuit are important basic circuits of DC-DC converters. An integrated circuit of these four circuits has been developed and presented in this paper. The integrated circuit was developed according to the rules of thumb. It can be applied to energy storage systems, uninterruptible power systems and charging systems to improve the application flexibility of these systems.

Keywords—Buck circuit, boost circuit, DC-DC converter.

INTRODUCTION

Non-isolated DC-DC converters are commonly used power converters in the industry [1]. They can change the level of DC voltage according to the needs of users and provide qualified DC power to the loads [2]. Non-isolated DC-DC converters include four circuits, namely buck circuit, boost circuit, buck/boost circuit and Cuk circuit, where the buck circuit is used to reduce the level of the input voltage, the boost circuit is used to increase the level of the input voltage, the buck/boost circuit is used to reduce or increase the level of the input voltage, and the Cuk circuit is an improved circuit of the buck/boost circuit, which can also be used to reduce or increase the level of the input voltage [3,4].

Non-isolated DC-DC converters are widely used in industrial products due to their simple topologies and stable performance. However, with the progress of the times, the application of energy storage systems, uninterruptible power systems, and charging systems has become more and more popular [5,6]. The topologies of conventional non-isolated DC-DC converters lacks the flexibility to change, making it difficult to meet the needs of the industry.

For this reason, an integrated circuit of non-isolated DC-DC converters was developed and presented here. The integrated circuit was developed using rules of thumb. It has the function of variable topology. Users can obtain the topology of a buck, a boost, a buck/boost or a Cuk circuit through the control of switches. The integrated circuit has the flexibility of variable topology and then can meet the needs of the storage systems, uninterruptible power systems, and charging systems.

CIRCUIT DESIGN

The topology of the developed integrated circuit is shown in Fig. 2. The topology includes the circuits of a buck converter, a boost converter, a buck/boost converter and a Cuk converter. There are thirteen switches, named SW₁ to SW₁₃, in the integrated circuit. Every relay has a normally closed contact and a normally open contact. The thirteen relays can be used to change the topology of the integrated circuit, so that

the integrated circuit can become a buck circuit, a boost circuit, a buck/boost circuit or a Cuk circuit. Moreover, an N-channel MOSFET Q₁ is used as an electronic switch to change the charge and discharge state of the inductors. The control rules are described as follows.

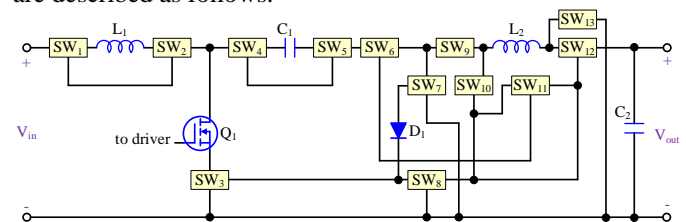


Fig. 1. The topology of the developed integrated circuit.

A. Buck mode

The microcontroller changes the original states of relays SW₁, SW₂, SW₃, SW₇, SW₈, SW₉ and SW₁₀ and keeps the original states of other relays, then the topology of the integrated circuit becomes a buck circuit, as shown in Fig. 2. The output voltage of this buck circuit is shown in formula (1). The output voltage is lower than the input voltage when the duty cycle D is less than 100%.

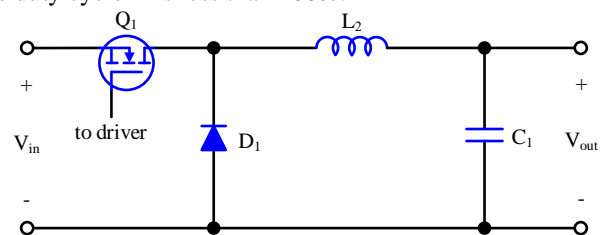


Fig. 2. The topology of the buck circuit changed from the integrated circuit.

Fig. 3.

$$V_{out} = D \times V_{in} \quad (1)$$

Where

V_{in} is the input voltage;

V_{out} is the output voltage;

D is the duty cycle.

B. Boost mode

The microcontroller changes the original states of relays SW₄, SW₅, SW₈, SW₉, SW₁₁ and SW₁₂ and keeps the original states of other relays, then the topology of the integrated circuit becomes a boost circuit, as shown in Fig. 3. The output voltage of this boost circuit is shown in formula (2), and the output voltage is lower than the input voltage when the duty cycle D is greater than 0%.

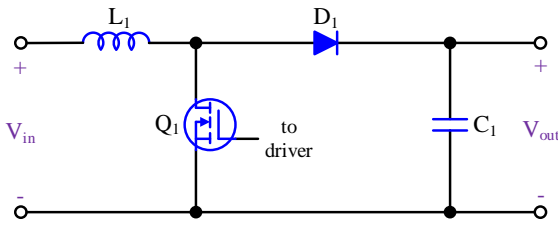


Fig. 4. The topology of the boost circuit changed from the integrated circuit.

$$V_{out} = \frac{1}{1-D} \times V_{in} \quad (2)$$

C. Buck/Boost mode

The microcontroller changes the original states of relays $SW_1, SW_2, SW_3, SW_6, SW_8, SW_9, SW_{10}, SW_{12}$ and SW_{13} and keeps the original states of other relays, then the topology of the integrated circuit becomes a buck/boost circuit, as shown in Fig. 4. The output voltage of this buck/boost circuit is shown in formula (3). The output voltage is lower than the input voltage when the duty cycle D is less than 50%, and the output voltage is greater than the input voltage when the duty cycle D is greater than 50%.

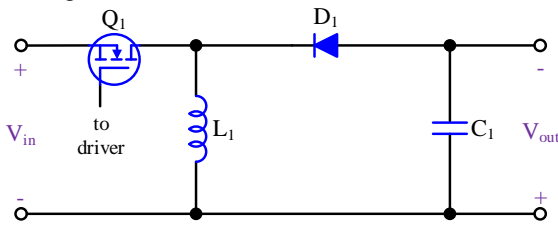


Fig. 5. The topology of the buck/boost circuit changed from the integrated circuit.

$$V_{out} = -\frac{D}{1-D} \times V_{in} \quad (3)$$

D. Cuk mode

The microcontroller keeps the original states of all relays, then the topology of the integrated circuit is a Cuk circuit, as shown in Fig. 5. The characteristics of the Cuk circuit are the same as that of the buck/boost circuit, so its output voltage is also the formula (3). The output voltage is lower than the input voltage when the duty cycle D is less than 50%, and the output voltage is greater than the input voltage when the duty cycle D is greater than 50%.

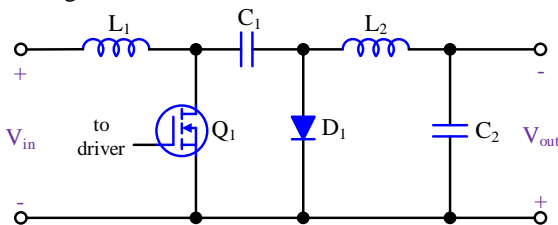


Fig. 6. The topology of the Cuk circuit changed from the integrated circuit.

PERFORMANCE TEST

Fig. 6 shows the functional block diagram of the developed integrated circuit for testing. The relay drivers are used to drive the relays SW_1 to SW_{13} . The MOSFET driver is used to drive the MOSFET Q_1 .

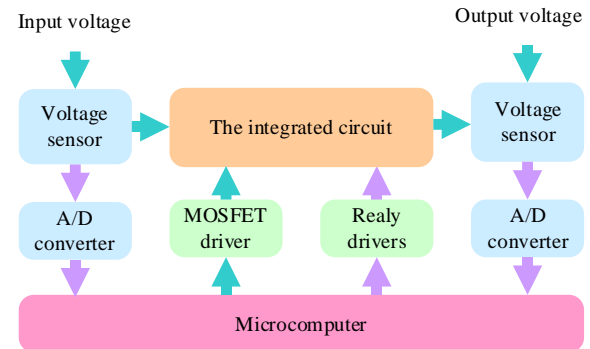


Fig. 7. The functional block diagram of the developed integrated circuit.

Fig. 7 shows the prototype of the developed integrated circuit. The microcontroller used by this research is a STM32 chip. The MOSFET Q_1 is an N channel NexFET power MOSFET. The MOSFET driver is LM5106MM. The relays are G6S-2 and the relay drivers are NPN transistors S8050.

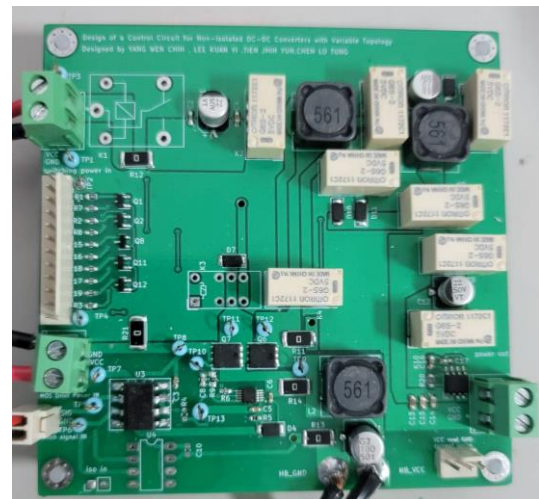


Fig. 8. A photo of the physical circuit of the developed integrated circuit.

In order to examine the performance of the developed integrated circuit, four test cases were carried out in this research. The test conditions and test results are explained as follows.

A. Buck mode

When the microcontroller drives relays $SW_1, SW_2, SW_3, SW_7, SW_8, SW_9$ and SW_{10} to the normally open state and drives the relays $SW_4, SW_5, SW_6, SW_{11}, SW_{12}$ and SW_{13} to the normally closed state, the integrated circuit enters the buck mode. At this test case, the microcontroller sent a PWM signal to the MOSFET Q_1 . The frequency of the PWM signal was 150kHz and the duty cycle is 37.5%. The test results of the developed integrated circuit are shown in Fig. 8. The input voltage of the developed integrated circuit was 19.2V and the output voltage was 6.44V. The output voltage was indeed less than the input voltage. The integrated circuit therefore did work in buck mode.



Fig. 9. The test results of the integrated circuit working in buck mode.

B. Boost mode

When the microcontroller drives relays SW₄, SW₅, SW₈, SW₉, SW₁₁ and SW₁₂ to the normally open state and drives the relays SW₁, SW₂, SW₃, SW₆, SW₇, SW₁₀ and SW₁₃ to the normally closed state, the integrated circuit enters the boost mode. At this test case, the microcontroller sent a PWM signal to the electronic switch Q₁. The frequency of the PWM signal was 150kHz and the duty cycle is 16.9%. The test results of the developed integrated circuit are shown in Fig. 9. The input voltage of the developed integrated circuit was 5.6V and the output voltage was 16.4V. The output voltage was indeed greater than the input voltage. The integrated circuit therefore did work in boost mode.

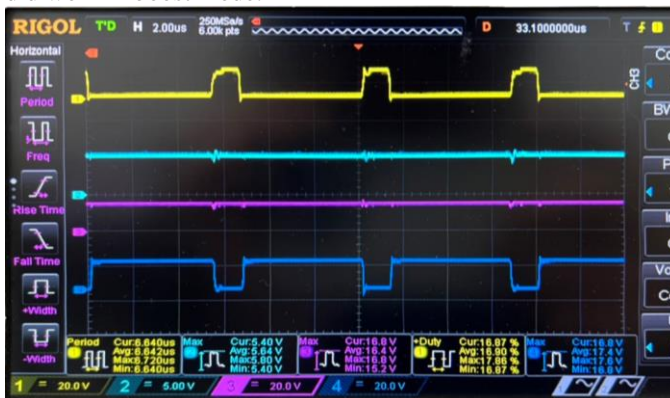


Fig. 10. The test results of the integrated circuit working in boost mode.

C. Buck/Boost mode

When the microcontroller drives relays SW₁, SW₂, SW₃, SW₆, SW₈, SW₉, SW₁₀, SW₁₂ and SW₁₃ to the normally open state and drives the relays SW₄, SW₅, SW₇ and SW₁₁ to the normally closed state, the integrated circuit enters the boost mode. This test case contains two sub-cases. In the first sub-case, the microcontroller sent a PWM signal to the electronic switch Q₁. The frequency of the PWM signal was 150kHz and the duty cycle is 24.1%. The test results of the developed integrated circuit are shown in Fig. 10. The input voltage of the developed integrated circuit was 24.5V and the output voltage was 9.6V. The output voltage was indeed less than the input voltage. The integrated circuit therefore did work in buck mode. In the second sub-case, the microcontroller still sent the same PWM signal to the electronic switch Q₁. The frequency of the PWM signal was 150kHz and the duty cycle is 65.3%. The test results of the developed integrated circuit are shown

in Fig. 11. The input voltage of the developed integrated circuit was 5.4V and the output voltage was 55.1V. The output voltage was indeed greater than the input voltage. The integrated circuit therefore did work in boost mode.



Fig. 11. The test results of the integrated circuit working in buck mode of the buck/boost mode.



Fig. 12. The test results of the integrated circuit working in boost mode of the buck/boost mode.

D. Cuk mode

When the microcontroller keeps all relays in the normally closed state, the integrated circuit enters the Cuk mode. This test case also contains two sub-cases. In the first sub-case, the microcontroller sent a PWM signal to the electronic switch Q₁. The frequency of the PWM signal was 150kHz and the duty cycle is 16.87%. The test results of the developed integrated circuit are shown in Fig. 12. The input voltage of the developed integrated circuit was 5.63V and the output voltage was 2.18V. The output voltage was indeed less than the input voltage. The integrated circuit therefore did work in buck mode. In the second sub-case, the microcontroller still sent the same PWM signal to the electronic switch Q₁. The frequency of the PWM signal was 150kHz and the duty cycle is 60.68%. The test results of the developed integrated circuit are shown in Fig. 13. The input voltage of the developed integrated circuit was 5.72V and the output voltage was 16.8V. The output voltage was indeed greater than the input voltage. The integrated circuit therefore did work in boost mode.



Fig. 13. The test results of the integrated circuit working in buck mode of the Cuk mode.



Fig. 14. The test results of the integrated circuit working in boost mode of the Cuk mode.

CONCLUSIONS

In recent years, the use of energy storage systems, uninterruptible power systems and charging systems has become more and more common [7]. Energy storage systems, uninterruptible power systems and charging systems must use

DC-DC converters to convert voltage levels in order to provide qualified power for loads. Since there are various types of DC-DC converters, it causes a lot of inconvenience in manufacture and application [8].

This research has developed an integrated circuits of four non-isolated DC-DC converters based on the rules of thumb. The developed integrated circuit can provide the power conversion function of buck mode, boost mode, buck/boost mode or Cuk mode according to the needs of users. The developed integrated circuit has the function of variable topology. It is very convenient to use and can improve the application flexibility of the non-isolated DC-DC converters.

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